

*East Search  
for paper no. 6*

L Number	Hits	Search Text	DB	Time Stamp
1	2	5708284.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/16 13:01
2	2	5798548.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/16 13:01
3	2	5959879.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/16 13:01
4	2	6172392.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/16 13:02
5	1	6420742.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/16 13:06
6	1063	schlosser.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/16 13:07
7	2	6438022.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/16 13:07
8	1	2000-225434.NRAN.	DERWENT	2002/09/16 13:07
-	3672	(257/314-326).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 10:50
-	91	((257/314-326).CCLS.) and ferroelectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/12 16:42
-	2	((257/314-326).CCLS.) and FEM adj gate adj unit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/12 16:45
-	22	FEM adj gate adj unit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/12 17:08
-	2235	((257/295) or (438/3) or (365/145)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/12 17:17
-	139	((257/295) or (438/3) or (365/145)).CCLS.) and floating adj gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/12 17:18

-	63	(((257/295) or (438/3) or (365/145)).CCLS.) and floating adj gate) and gate adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/12 17:27
-	6	macronix and ferroelectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/12 17:30
-	62	lung and ferroelectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/12 17:44
-	76	(((257/295) or (438/3) or (365/145)).CCLS.) and floating adj gate) not (((257/295) or (438/3) or (365/145)).CCLS.) and floating adj gate) and gate adj oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/12 17:44
-	256	(438/279).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:01
-	163	(257/389).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:02
-	2	((257/389).CCLS.) and ferroelectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:02
-	15	((257/389).CCLS.) and floating	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:10
-	2	("4598460"   "4713142").PN.	USPAT	2002/09/13 10:03
-	31	4833514.URPN.	USPAT	2002/09/13 10:03
-	2	((257/389).CCLS.) and ferroelectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:10
-	1	((438/279).CCLS.) and ferroelectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:12
-	9	("4236166"   "4550489"   "4740826"   "4788158"   "5398200"   "5414655"   "5451800"   "5497017"   "5670803").PN.	USPAT	2002/09/13 10:10
-	4	5963800.URPN.	USPAT	2002/09/13 10:11
-	42	((438/279).CCLS.) and floating	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:17
-	1	((257/389).CCLS.) and ((438/279).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:17

-	1	((257/389).CCLS.) and ((438/279).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:18
-	22	fem adj gate adj unit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:19
-	0	(fem adj gate adj unit) and (drain adj side drain-side)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:19
-	67	ferroelectric and (drain adj side drain-side)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:33
-	87	("5731608" "5932904" "5942776" "5962884" "6011285" "6018171" "6048738" "6117691" "6146904" "5907762" "6242771" "5801986" "5373462" "5856688" "5978253" "5808929" "5822239" "5930161" "5959879" "5383150" "5638319" "5708284" "5796139" "5796134" "5828092" "5869860" "5879982" "5889696" "5932903" "6046926" "6075264" "6080616" "6083765" "6141238" "6151242" "6194754" "6198651" "6205048" "6222756" "6225655" "6222756" "6225655" "6232169" "6236588" "6252793" "6294805" "6317380" "6320782" "6337216" "6337805") [pn]	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:42

-	607	ferroelectric and (iridium adj oxide "iro.sub.2")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:45
-	346	(ferroelectric and (iridium adj oxide "iro.sub.2")) and memory adj cell	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 10:46
-	185	((ferroelectric and (iridium adj oxide "iro.sub.2")) and memory adj cell) and polarization	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 11:02
-	102	((((ferroelectric and (iridium adj oxide "iro.sub.2")) and memory adj cell) and polarization) and (gate adj oxide gate adj insulator gate adj insulating)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 11:03
-	14	(((((ferroelectric and (iridium adj oxide "iro.sub.2")) and memory adj cell) and polarization) and (gate adj oxide gate adj insulator gate adj insulating)) and (spacer sealing seal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 11:21
-	14	("4888630"   "5300799"   "5412596"   "5515311"   "5517445"   "5523964"   "5541871"   "5559733"   "5623439"   "5753946"   "5768185"   "5822239"   "5822240"   "5856688").PN.	USPAT	2002/09/13 11:06
-	8	5959879.URPN.	USPAT	2002/09/13 11:06
-	10	"5780886"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 11:30
-	7	5780886.URPN.	USPAT	2002/09/13 11:21
-	5	("5146299"   "5434102"   "5478653"   "5519234"   "5576564").PN.	USPAT	2002/09/13 11:21
-	29	("5604357" "5780886" "5989927" "6011285" "5907762" "6048738" "5731608" "6194752" "5959879" "5986298" "6194270" "5768185" "5753946" "6141238") [pn] jp-08111086-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 12:27
-	80	ferroelectric adj memory and polarization with drain	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 12:28
-	10	("4888630"   "5046043"   "5229309"   "5300799"   "5303182"   "5416735"   "5440173"   "5495117"   "5498888"   "5559733").PN.	USPAT	2002/09/13 12:37
-	20	5708284.URPN.	USPAT	2002/09/13 12:38
-	22	substrate and "5708284"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 14:58
-	0	substrate and "5708284.pn."	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 14:58

-	2	substrate and 5708284.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:00
-	1	substrate with conductivity and 5708284.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:22
-	2235	((365/145) or (438/3) or (257/295)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:48
-	1	((365/145) or (438/3) or (257/295)).CCLS.) and (advantage improv\$6 reduc\$3 inhibit\$3) with shar\$3 adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:51
-	1	((365/145) or (438/3) or (257/295)).CCLS.) and (advantage improv\$6 reduc\$3 inhibit\$3) with common adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:51
-	3672	(257/314-326).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:52
-	1	((365/145) or (438/3) or (257/295)).CCLS.) and (advantage improv\$6 reduc\$3 inhibit\$3) with shar\$3 adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:54
-	6	((365/145) or (438/3) or (257/295)).CCLS.) and (advantage improv\$6 reduc\$3 inhibit\$3) with shar\$3 with source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:55
-	0	((257/314-326).CCLS.) and (advantage improv\$6 reduc\$3 inhibit\$3) with common adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:55
-	32	((257/314-326).CCLS.) and (advantage improv\$6 reduc\$3 inhibit\$3) with common adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:56
-	0	((438/279).CCLS.) and ferroelectric and (advantage improv\$6 reduc\$3 inhibit\$3) with common adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:57
-	4	((438/279).CCLS.) and (advantage improv\$6 reduc\$3 inhibit\$3) with shar\$3 with source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 15:59
-	5	((438/279).CCLS.) and (advantage improv\$6 reduc\$3 inhibit\$3) with common adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 16:01
-	0	((438/279).CCLS.) and ferroelectric and (advantage improv\$6 reduc\$3 inhibit\$3) with shar\$3 with source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 16:02

-	28	((257/314-326).CCLS.) and (advantage improv\$6 reduc\$3 inhibit\$3) with shar\$3 with source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:11
-	3	"6438022"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 17:00
-	1	2000-225434.NRAN.	DERWENT	2002/09/13 16:19
-	7	("672408" "4092185") [pn]	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 17:01
-	4	("4672408" "4092185") [pn]	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 17:05
-	99	substrate with conventional\$2 with conductivity with well	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 17:17
-	0	(substrate with conventional\$2 with conductivity with well) and ferroelectrc	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 17:17
-	0	(substrate with conventional\$2 with conductivity with well) and ferroelectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 17:18
-	69	(substrate with conventional\$2 with conductivity with well) and (257/\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 17:18
-	14	((substrate with conventional\$2 with conductivity with well) and (257/\$3)) and floating	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/13 17:19
-	7	bulk with substrate with first adj conductivity with opposite with (source drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 10:53
-	4	ferroelectric and substrate with first adj conductivity with opposite with (source drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 11:03
-	0	"5708234" and isolat\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 11:04
-	8	"5708284" and isolat\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 11:04

-	256	(438/279).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 11:09
-	1	((438/279).CCLS.) and ferroelectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 11:10
-	10	chips with plurality adj transistor with interconnected	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:14
-	1297	cable with plurality adj wire	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:14
-	62	(cable with plurality adj wire) and chip	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:15
-	0	((cable with plurality adj wire) and chip) and plurality adj transistro	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:15
-	2	((cable with plurality adj wire) and chip) and plurality adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:27
-	786	(257/295).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:27
-	5	((257/295).CCLS.) and spacer with (silicon adj oxide "sio.sub.2") with (silicon adj nitride "si.sub.3 n.sub.4" aluminum adj oxide alumina "al.sub.2o.sub.3")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:44
-	256	channel adj length with ("0.18" "0.35")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:45
-	0	channel adj length with (".18" ".35")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:46
-	0	channel adj length with (".18" ".35") with micron	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:47
-	111	(channel adj length with ("0.18" "0.35")) and 257/\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:52
-	0	(channel adj length with ("0.18" "0.35")) and 257/295	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:48

-	3	(channel adj length with ("0.18" "0.35")) and 438/3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:49
-	7	(channel adj length with ("0.18" "0.35")) and ferroelectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:49
-	4	((channel adj length with ("0.18" "0.35")) and ferroelectric) not ((channel adj length with ("0.18" "0.35")) and 438/3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:49
-	0	(channel adj length with ("0.18" "0.35")) and 365/145	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:50
-	3672	(257/314-326).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 12:53
-	14	(channel adj length with ("0.18" "0.35")) and ((257/314-326).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 16:55
-	786	(257/295).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 16:55
-	19	((257/295).CCLS.) and sti	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 16:56
-	2	((257/295).CCLS.) and sti) not ((257/295).CCLS.) and shallow adj trench adj isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 16:56
-	20	((257/295).CCLS.) and shallow adj trench adj isolation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 16:59
-	0	active with inactive with region with shallow adj trench adj isolation with (conventionally typically generally usually)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 17:02
-	0	active with inactive with region same shallow adj trench adj isolation with (conventionally typically generally usually)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:00
-	10	(purpose objective) with well and ((257/295).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:05
-	910	(advantage improve\$4 reduc\$4 inhibit\$3) with well near3 conductivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:06



-	1	((advantage improve\$4 reduc\$4 inhibit\$3) with well near3 conductivity) and 257/295	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:08
-	0	438/3 and ((advantage improve\$4 reduc\$4 inhibit\$3) with well near3 conductivity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:09
-	1	365/145 and ((advantage improve\$4 reduc\$4 inhibit\$3) with well near3 conductivity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:09
-	3672	(257/314-326).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:09
-	0	(365/145 and ((advantage improve\$4 reduc\$4 inhibit\$3) with well near3 conductivity)) and ((257/314-326).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:09
-	3	((advantage improve\$4 reduc\$4 inhibit\$3) with well near3 conductivity) and ((257/314-326).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:14
-	7	conductivity adj substrate and 257/295	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:17
-	1	conductivity adj substrate and 438/3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:17
-	5	conductivity adj substrate and 365/145	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:18
-	0	(conductivity adj substrate and ((257/314-326).CCLS.)) and ferroelectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:18
-	43	conductivity adj substrate and ((257/314-326).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:27
-	1203	conductivity near3 substrate with opposite with source with drain	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:31
-	9	(conductivity near3 substrate with opposite with source with drain) and 257/295	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:29
-	6	(conductivity near3 substrate with opposite with source with drain) and 438/3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:30

-	8	(conductivity near3 substrate with opposite with source with drain) and 365/145	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:30
-	8	conductivity near1 substrate and 257/295	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:32
-	2	conductivity near1 substrate and 438/3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:33
-	6	conductivity near1 substrate and 365/145	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:34
-	76	conductivity near1 substrate and ((257/314-326).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:46
-	4	("4672408" "4092185") [pn] and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/14 18:46